Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.670 inches

Terminal Length:

0.210 millimeters

Overall Width:

0.210 inches

End Application:

6625-01-443-0552

Mounting Facility Quantity:

3

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

15.0 breakdown voltage, collector to emitter, sustained and 15.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current

Power Rating Per Characteristic:

600.0 milliwatts small-signal output power, common-base preset

Maximum Operating Tempurature Per Measurement Point:

-55.0 degrees celsius case and 150.0 degrees celsius case

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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